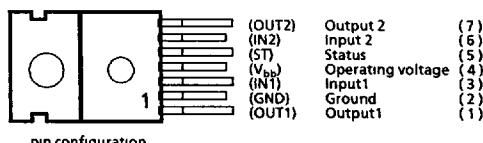


TWO CHANNEL PROFET®

- Two independent high-side switches
- Overtemperature protection for each channel
- Overload protection for each channel
- Short circuit protection by overtemperature protection²⁾
- Overvoltage protection
- Input protection
- Clamp of negative output voltage with inductive loads
- Open load detection in ON-state
- Short to V_{bb} or open load detection in OFF-state
- Maximum current internally limited
- Protection against loss of ground
- Undervoltage shutdown with reset and hysteresis
- Overvoltage shutdown with reset and hysteresis
- Open drain status feedback
- Electrostatic discharge (ESD) protection

Description PROFET® an intelligent power switch with integrated protection against self-destruction
Application Power switch for all kinds of loads.

Case Plastic package, similar to TO 220
 Pin 4 is shorted to the mounting flange



TO220 / 7

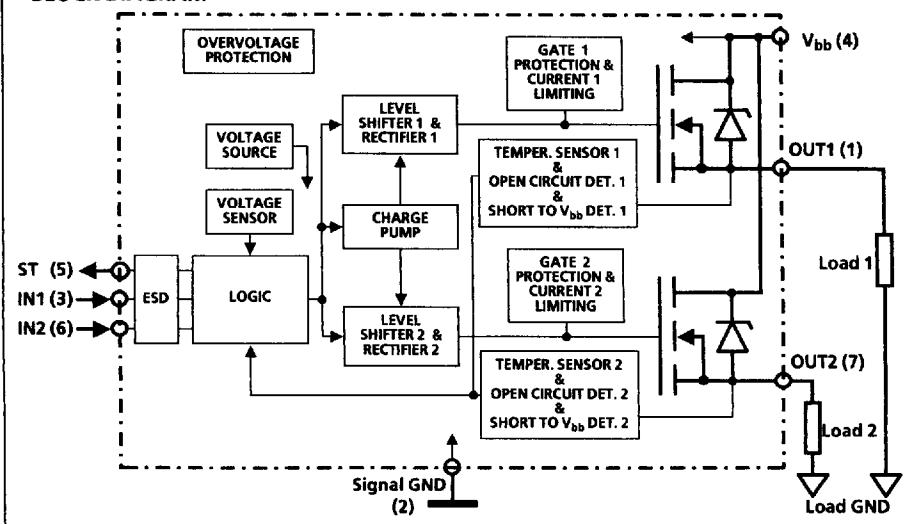
Type	Ordering code
BTS 621	C67078-55506-A2

¹⁾ internal active clamp²⁾ Valid for 12 V applications only. For 24 V application available from middle of 1994 onwards.

MAXIMUM RATINGS

DESCRIPTION	SYMBOL	RATINGS	UNIT	CONDITIONS
Breakdown voltage	$V_{bb(AZ)}$ ¹⁾	>40	V	$T_i = -40\dots+150^\circ\text{C}, I_{bb} = 1\text{mA}$
Short circuit current	I_{SC}	self-limited		
Max. power dissipation	P_D	75	W	$T_C = 25^\circ\text{C}$
Operating temperature range	T_i	-40...+150	°C	
Storage temperature range	T_{stg}	-55...+150	°C	
Status-pin current	I_{ST}	5	mA	
Thermal resistance				
Chip - case	$R_{th JC}$	1.67	K / W	for both channels
Chip - case	$R_{th JC}$	ca. 3.1	K / W	for each channel
Chip - ambient	$R_{th JA}$	75	K / W	

BLOCK DIAGRAM



Description	Symbol	Characteristics			Unit	Conditions
		min.	typ.	max.		
Drain-source on-state resistance (Pin 4 to 7/1)	$R_{DS(on)}$	-	-	100	$\text{m}\Omega$	$V_{bb} = 12 \text{ V}, I_L = 2 \text{ A}$
Operating voltage (Pin 4 to 2)	V_{bb}	5.8	-	34	V	$T_j = -40 \dots +150^\circ\text{C}$
Nominal current, calculated value (Pin 7/1 to GND)	I_{L-ISO}	3.5	-	-	A	ISO-proposal: $V_{bb} - V_{out} \leq 0.5 \text{ V}$, $T_c = 85^\circ\text{C}$
Load current, theoretical value (Pin 7/1 to GND)	I_{L-MOS}	-	-	19	A	MOS-standard: $T_c = 25^\circ\text{C}$, $T_j = 150^\circ\text{C}$
Load current limit (Pin 7/1 to GND)	I_{LLim}	-	22	-	A	onset of active regulation when: $V_{bb} - V_{out} > 1 \text{ V}$
Standby current (Pin 4)	I_R	-	10	20	μA	$V_{bb} = 12 \text{ V}$
Voltage threshold for Short to V_{bb} or open load detection in OFF - state	V_{OC}	2	3	4	V	
Open load detection current in ON - state	I_{OL}	10	-	400	mA	
Input voltage (Pin 6/3 to 2)	$V_{in(off)}$ $V_{in(on)}$	-0.5 3.5	-	1.5 20	V	$V_{bb} = 12 \text{ V}$
Input current (Pin 6/3)	$I_{in(off)}$ $I_{in(on)}$	1 20	- 50	50 80	μA	$V_{in(off)} = 0.4 \text{ V}$ $V_{in(on)} = 2.5 \text{ V}$
Trip temperature	T_t	150	-	-	$^\circ\text{C}$	automatic shutdown
Slew rate	di/dt_{on} di/dt_{off}	0.01 0.01	-	0.1 0.1	$\text{A}/\mu\text{s}$	$V_{bb} = 12 \text{ V}$ Resistive Load $I_L = 2 \text{ A}$
Status (Open drain)	$V_{St(\text{high})}$ $V_{St(\text{low})}$	5 -	-	7 0.8	V	$I_{st} = 50 \mu\text{A}$ $I_{st} = 1.6 \text{ mA}, T_j = -40 \dots +150^\circ\text{C}$
Output to ground internal impedance Pin 7/1 to 2	R_i	5	-	20	$\text{k}\Omega$	$V_{OUT} < 5\text{V}$
negative inductive clamp voltage	V_{ind}	-	33	-	V	$V_{bb} = 12 \text{ V}$ $V_{ind} = V_{bb(AZ)} - V_{bb}$ $V_{bb(AZ)} = 45 \text{ V}_{typ}$
Reverse polarity (Pin 2 to 4) *	$-V_{bb}$	-	-	32	V	

*) Requires 150Ω resistor in GND connection. Reverse load current (through intrinsic drain-source diode) is normally limited by the connected load. Input and Status currents have to be limited. It is recommend that $15\text{k}\Omega$ resistors be inserted in series with IN and ST.

Truth table (priority given to activated (V_{IN} = high) channel in the event of status conflict)

		IN1	IN2	OUT1	OUT2	ST
Normal operation		L	L	L	L	H
		H	H	H	H	H
		L	H	L	H	H
		H	L	H	L	H
Undervoltage / Overvoltage		X	X	L	L	H
Overtemperature	Channel 1	H	X	L	X	L
	Channel 2	X	H	X	L	L
	Ch.1 / Ch.2	L	L	L	L	H
Open Load	Channel 1	H	X	H	X	L
		L	L	Z	L	H(L*)
		L	H	Z	H	H
	Channel 2	X	H	X	H	L
		L	L	L	Z	H(L*)
		H	L	H	Z	H
Output shorted to V_{bb}	Channel 1	H	X	H	X	H(L**)
		L	L	H	L	L
		L	H	H	H	H
	Channel 2	X	H	X	H	H(L**)
		L	L	L	H	L
		H	L	H	H	H

L = "Low" level

X = "Don't care"

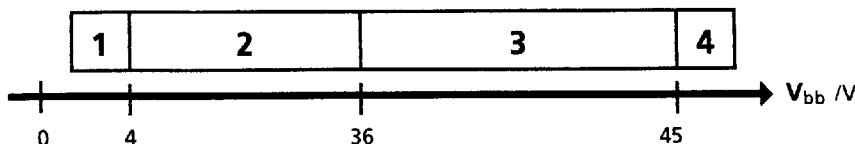
H = "High" level

Z = Potential defined by external impedance

Status timing : see applications

(*) With an additional external resistor (see circuits)

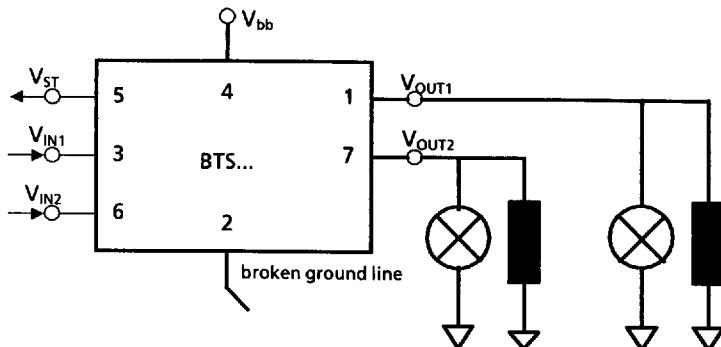
(**) Low resistance detected by open load detection circuit

Operating range (typ. at $T_j = 25^\circ\text{C}$)

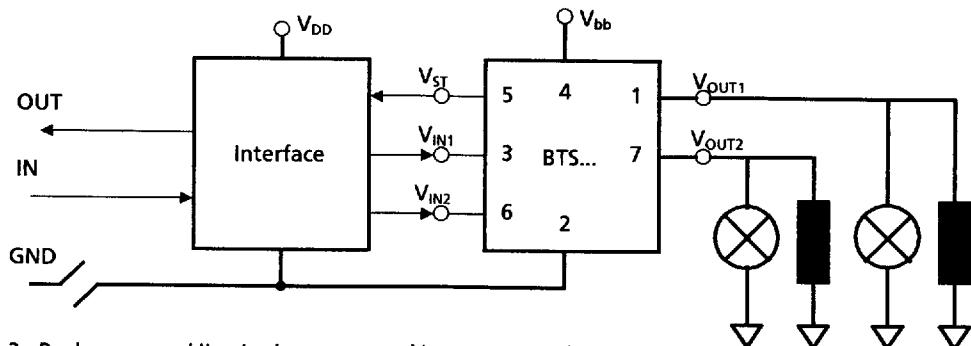
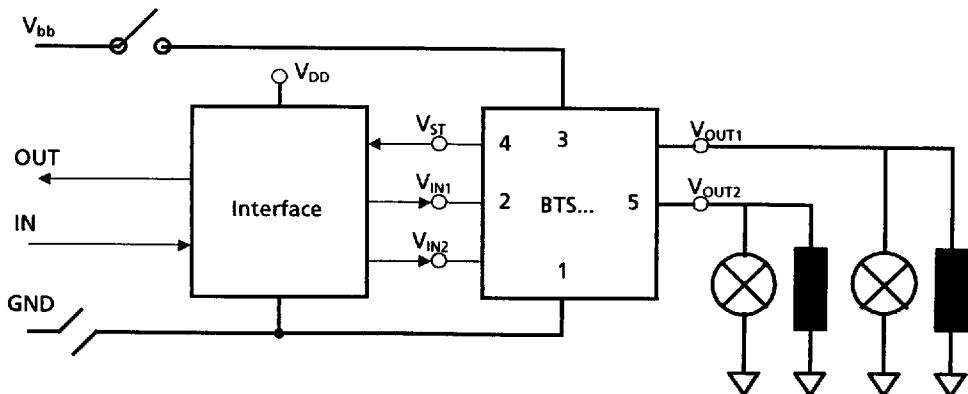
- 1: Undervoltage sensor causes the device to switch off
- 2: Normal operation
- 3: Overvoltage sensor causes the device to switch off
- 4: Increase of current between pin 4 and 2 from Zener diode to protect the circuit against overvoltage spikes

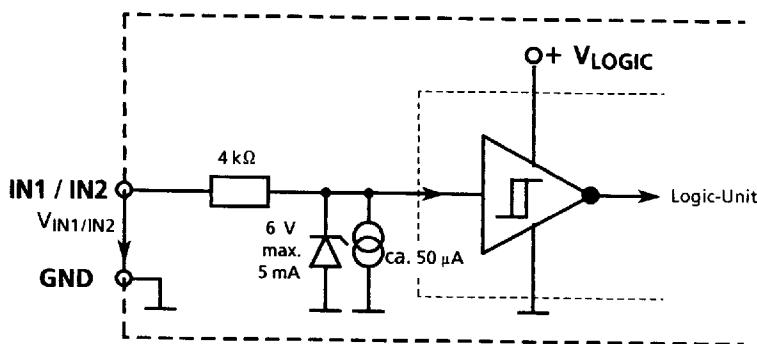
This power switch is fully protected against loss of ground (see below).
 By definition: no load current flows in the load despite loss of ground
 (only the current through the internal impedance R_i between PIN 7/1 to 2 flows).

1: Broken ground line at the BTS...

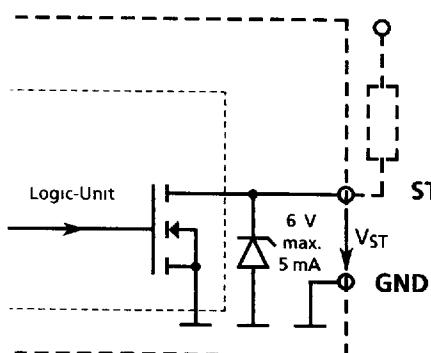


2: Broken ground line in the system, ground pulled high by Interface

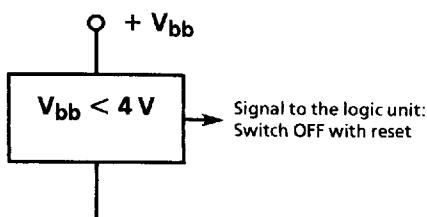
3: Broken ground line in the system and interruption of V_{bb} 

ESD Protected Logic-Inputs: IN1 / IN2 (3/6)**ESD Protected Status-Output: ST (5)**

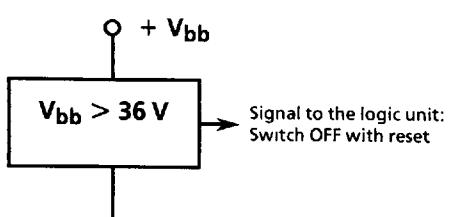
Open drain output with a typical output voltage of 6.0 V

**Voltage Sensor (typ. at $T_j = 25^\circ\text{C}$) :**

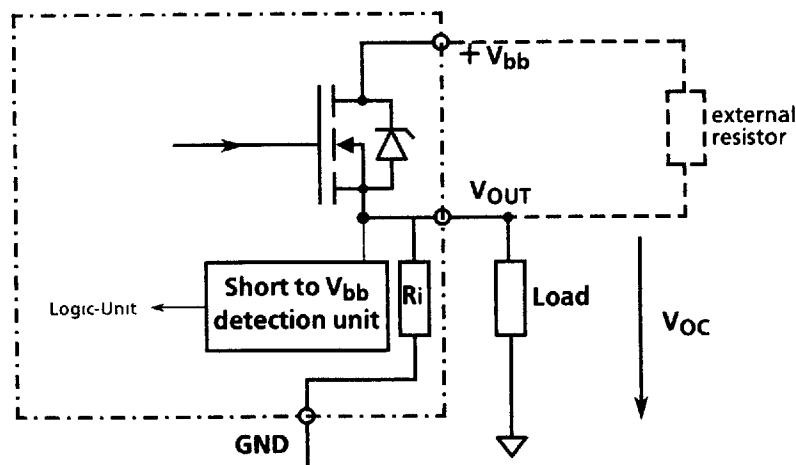
Undervoltage sensor



Ovvervoltage sensor

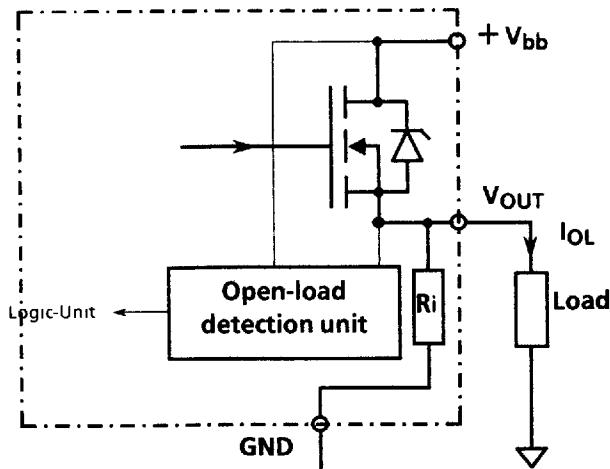


Short to V_{bb} or open load detection in OFF - state



The "Short to V_{bb} detection" unit monitors the voltage between OUT and GND (additional external resistor between V_{bb} and OUT required for open load detection in the OFF - state)

Open-load detection in ON - state



The "Open-load detection" unit monitors the voltage drop across the power transistor in the ON - state.

1: Switching lamp loads or inductive loads

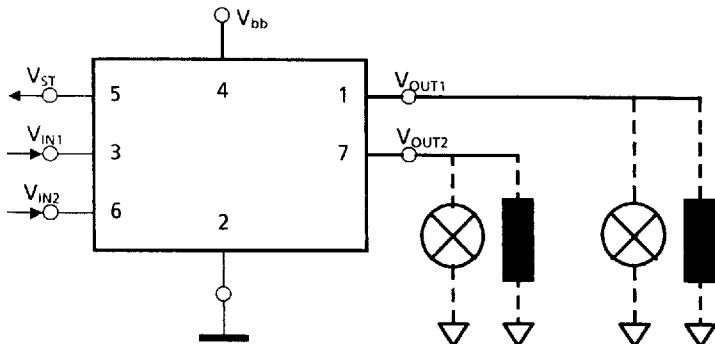
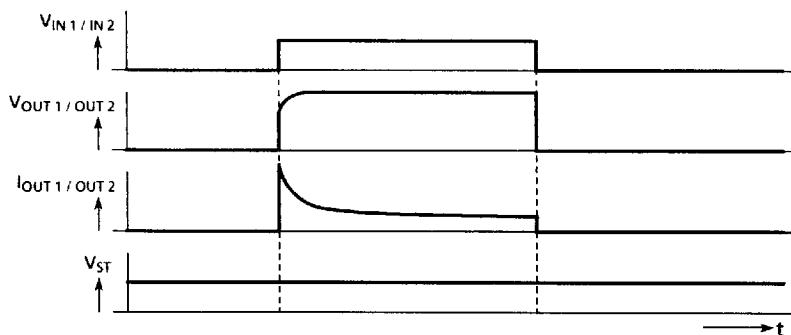
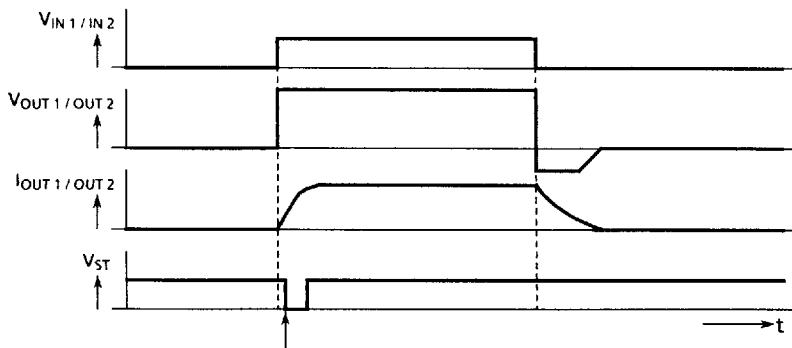


Diagram for each channel

lamp loads



inductive loads



Open load detection at switch-on depending on value of inductor

2: Operation with overload / overtemperature

Diagram is representative of each channel.

The channel not shown is in the OFF - state (normal operation)

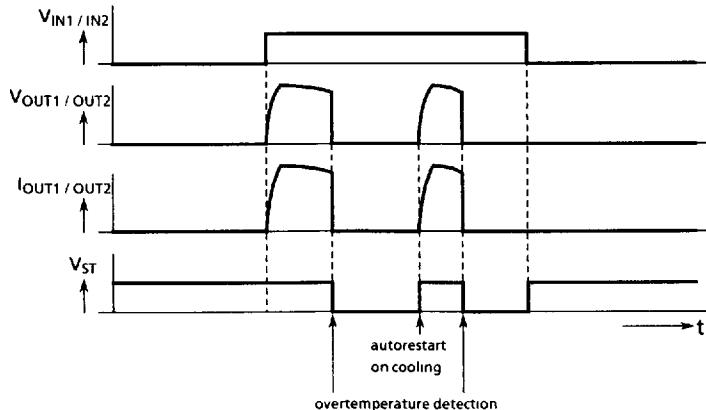
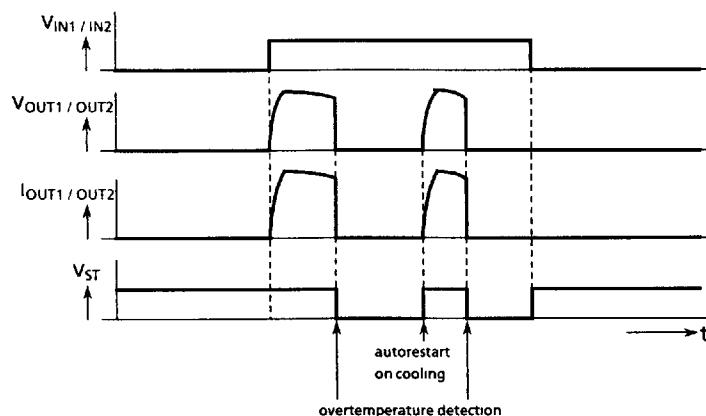


Diagram is representative of each channel.

The channel not shown is in the ON - state (normal operation)



3: Operation with open load

Diagram is representative of each channel.

The channel not shown is in the OFF - state (normal operation)

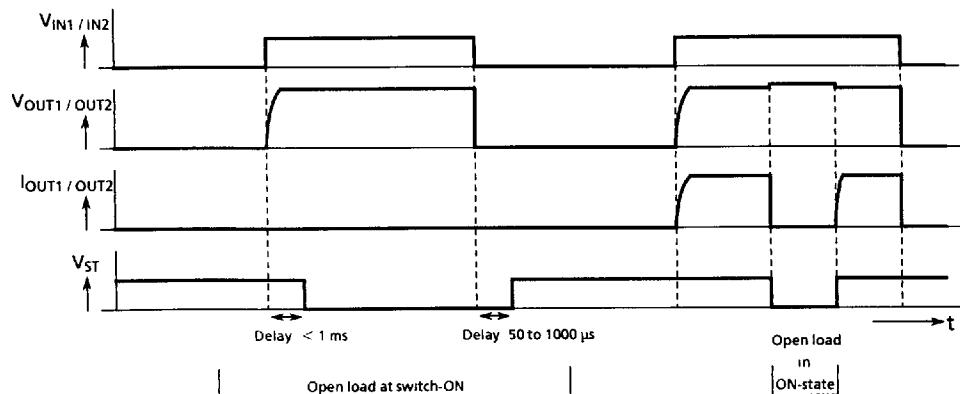
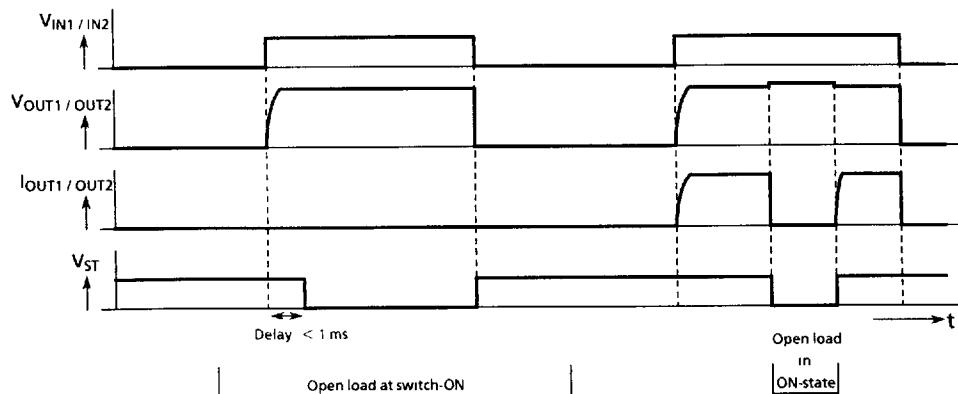


Diagram is representative of each channel.

The channel not shown is in the ON - state (normal operation)



- 4: Open load operation with additional external resistor between V_{bb} and OUT
 5: Operation with output short-circuited to V_{bb}

Diagram is representative of each channel.

The channel not shown is in the OFF - state (normal operation)

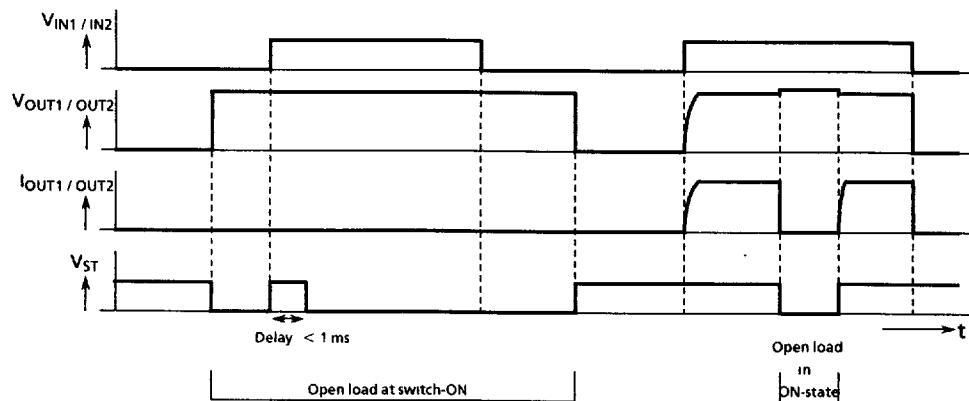


Diagram is representative of each channel.

The channel not shown is in the ON - state (normal operation)

